

Session Program

16-18 Nov 2009

15th RD50 Workshop

Strip Sensors

CERN, TE Auditorium

Tuesday 17 November

14:00

Strip Sensors

Session | Location: CERN, TE Auditorium

14:00–14:20 **First Results of SiBT test beam 2009**

Speaker

Jaakko Haerkoenen

14:20–14:40 **Interstrip resistance in silicon position-sensitive detectors**

Speaker

Dr Elena Verbitskaya

14:40–15:00

Charge collection annealing study of p-in-n silicon microstrip detectors

Speaker

Craig Wiglesworth

15:00–15:20

Annealing of Charge Collection Efficiency in highly irradiated MCz-n strip detectors.

Speaker

Mr Nicola Pacifico

15:20–15:40

Surface properties of ATLAS n-on-p sensors

Speaker

Hartmut Sadrozinski

15:40–16:10

Coffee break

16:10–16:30

Full-size ATLAS Sensor Testing (Late submission)

Speaker

Jan Bohm

16:30–16:50

Discussion on Strip Sensors (FDS)

16:50